# **Simulation Modeling**

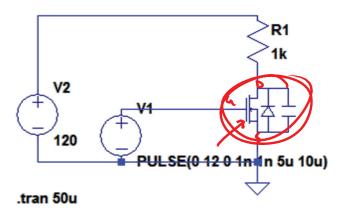


### **Circuit Simulation**

- LTSpice
  - Other tools accepted, but not supported
- Choose model type (switching, averaged, dynamic)
- Supplement analytical work rather than repeating it
- Show results which clearly demonstrate what matches and what does not with respect to experiments (i.e. ringing, slopes, etc.)



# **LTSpice Modeling Examples**

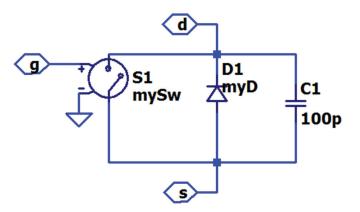


- Example files added to course materials page
  - Custom model
  - VDMOS model
  - Manufacturer Model



## **Custom Transistor Model**

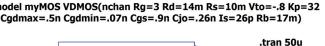
.model myD D(n=.001) .model mySw SW(Ron=10m Roff=1G Von=1 Voff = .5 )

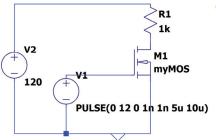




VC	OMOS	N	Ло	del	
Namo	Description		Units	Default	

Name	Description	Units	Default	Example	
Vto	Threshold voltage	v	0	1.0	
Кр	Transconductance parameter	A/V <sup>2</sup>	1.	.5	.m
Phi	Surface inversion potential	v	0.6	0.65	+
Lambda	Channel-length modulation	1/V	0.	0.02	-
mtriode	Conductance multiplier in triode region(allows independent fit of triode and saturation regions	-	1.	2.	
subthres	Current(per volt Vds) to switch from square law to exponential subthreshold conduction	A/V	0.	ln	м 
BV	Vds breakdown voltage	v	Infin.	40	
IBV	Current at Vds=BV	A	100pA	1u	
NBV	Vds breakdown emission coefficient	-	1.	10	•
Rd	Drain ohmic resistance	Ω	0.	1.	
Rs	Source ohmic resistance	Ω	0.	1.	
Rg	Gate ohmic resistance	Ω	0.	2.	
Rds	Drain-source shunt resistance	Ω	Infin.	10Meg	
Rb	Body diode ohmic resistance	Ω	0.	.5	
Cio	Zero-bias body diode	F	0.	1n	1





Note: any other parameters **ignored**E.g. ron = 3m Qg = 1n mfg = Infineon

http://ltwiki.org/LTspiceHelp/LTspiceHelp/M\_MOSFET.htm

# **Manufacturer Device Model**

- Text-only netlist model of device including additional parasitics and temperature effects
- May slow or stop simulation if timestep and accuracy are not adjusted appropriately



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# **Full Switching Simulation**

out .ic V(out)=0 .ic I(L1)=0 .lib switch.lib M2 R7 myMOS L1 10 C1 **R**2  $\tilde{\mathcal{O}}$ U1 R V1 С M1 **R8** myMOS

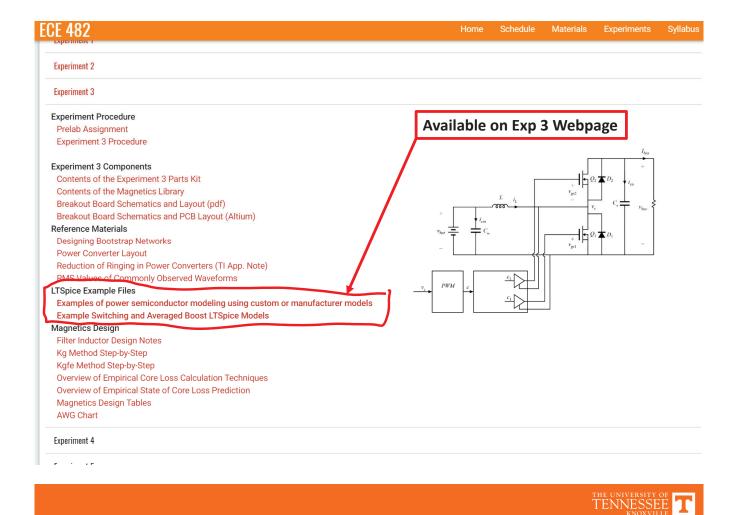
.model myMOS VDMOS(Rg=1 Vto=4.5 Rd=14m Rs=10m Rb=17m Kp=30 Cgdmax=.5p Cgdmin=.05n Cgs=.2n Cjo=.03n Is=88p) .tran 1

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## **Full Switching Simulation**

.model myMOS VDMOS(Rg=1 Vto=4.5 Rd=14m Rs=10m Rb=17m Kp=30 Cgdmax=.5p Cgdmin=.05n Cgs=.2n Cjo=.03n ls=88p) .tran 1 out .ic V(out)=0 .lib switch.lib Μ2 .ic I(L1)=0 **R7** Component Attribute Editor × 00 Open Symbol: E:\Program Files (x86)\LTC\LTspicelV\lib\sym\Custom\GateDi V1 This is the fourth attribute to appear on the netlist line. Attribute Value Vis. J Prefix Х InstName U1 Х GateDriver\_dt\_phase SpiceModel Value Value2 SpiceLin Spicel ine2 Cancel ΟK





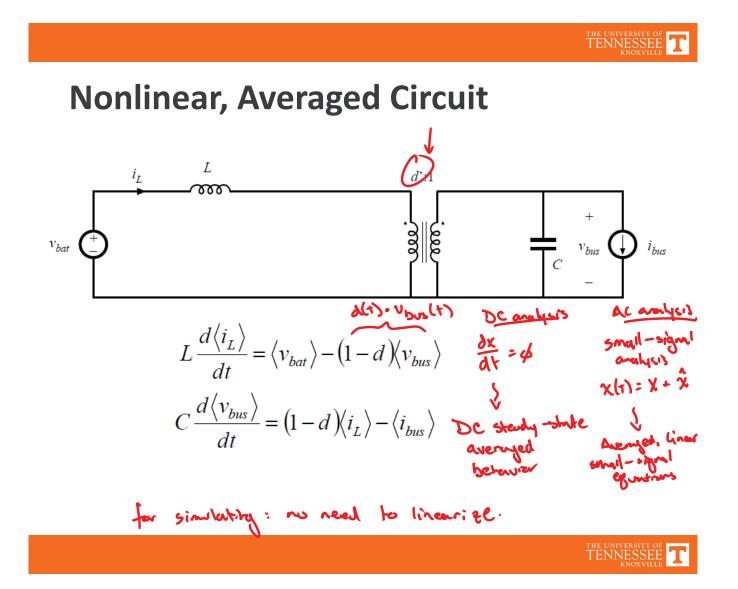
# **Full Switching Model**

- Gives valuable insight into circuit operation
  - Understand expected waveforms
  - Identify discrepancies between predicted and experimental operation
- Slow to simulate; significant high frequency content
- Cannot perform AC analysis

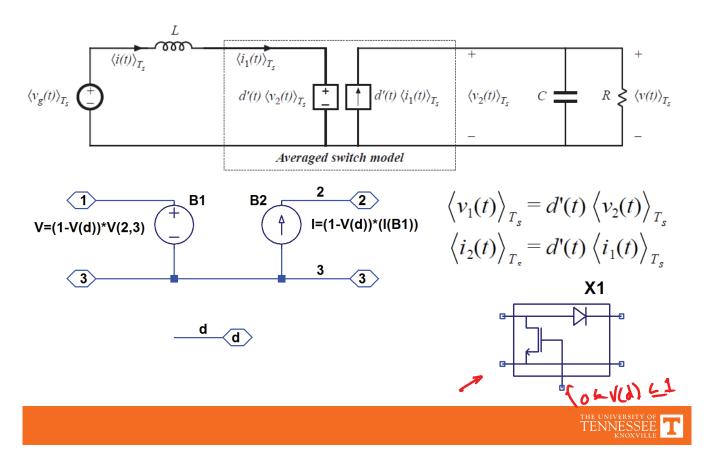


#### **Averaged Switch Modeling: Motivation**

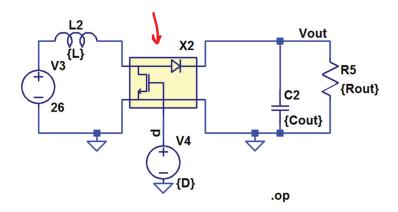
- A *large-signal, nonlinear* model of converter is difficult for hand analysis, but well suited to simulation across a wide range of operating points
- Want an *averaged* model to speed up simulation speed
- Also allows linearization (AC analysis) for control design



# **Implementation in LTSpice**

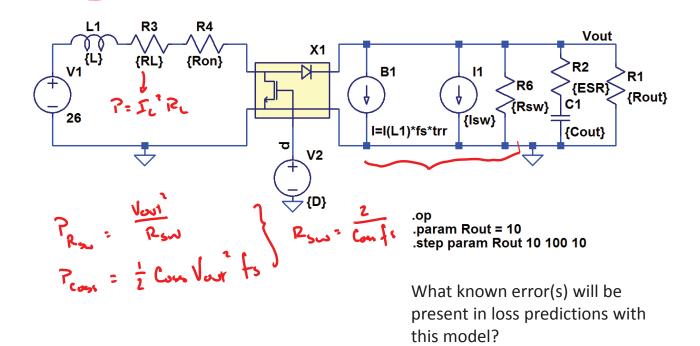


#### **Averaged Switch Model**





# Averaged Model With Losses

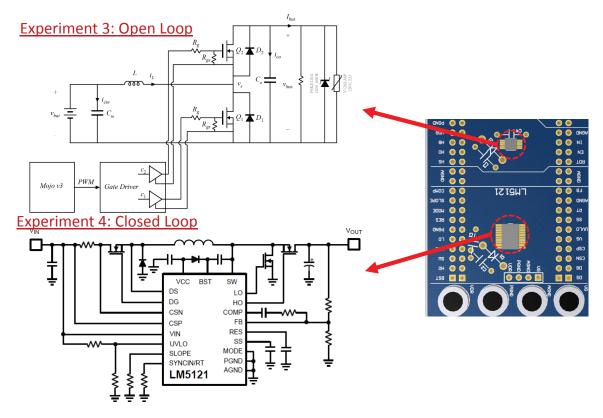




## **Experiment 4**

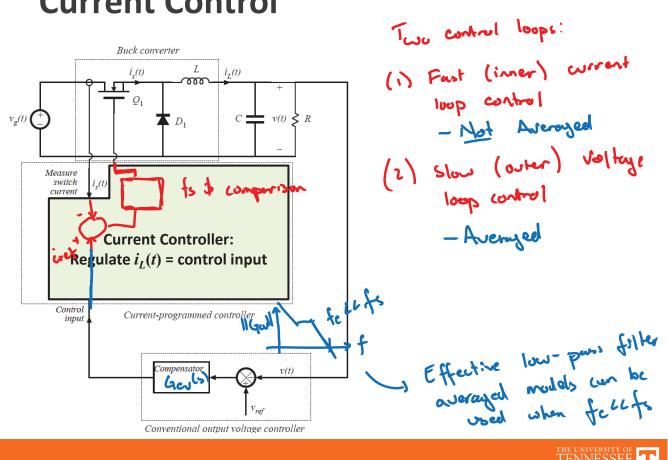


#### **Experiment 4: Closed-Loop Boost**



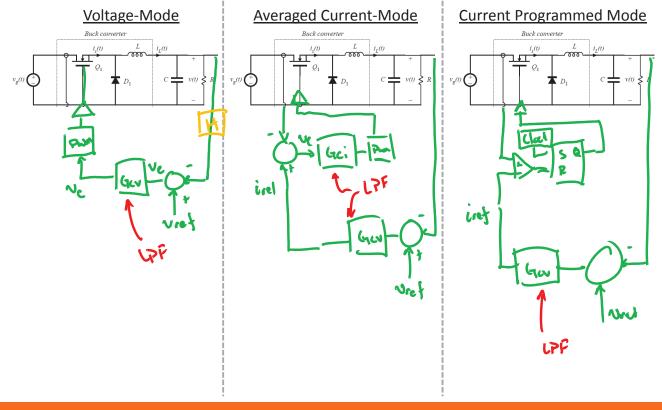


#### **Current Control**



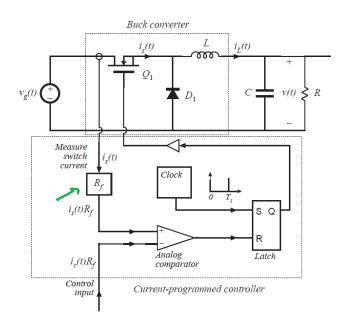
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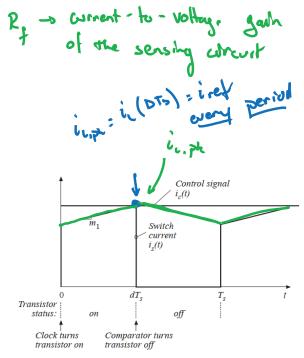
## **Averaged vs CPM**



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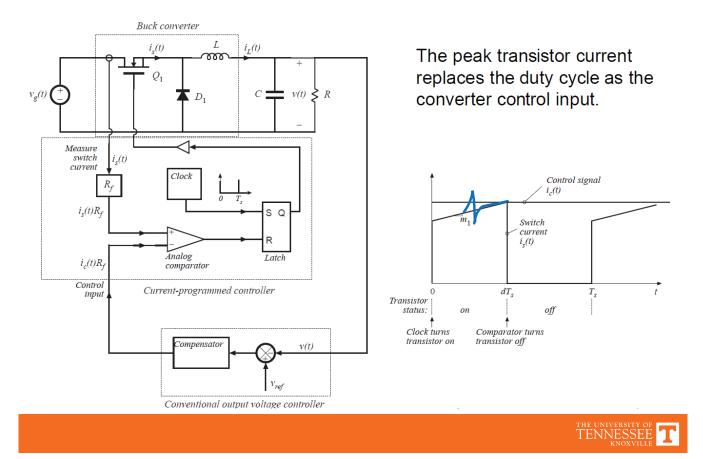
#### **Current Programmed Control (CPM)**





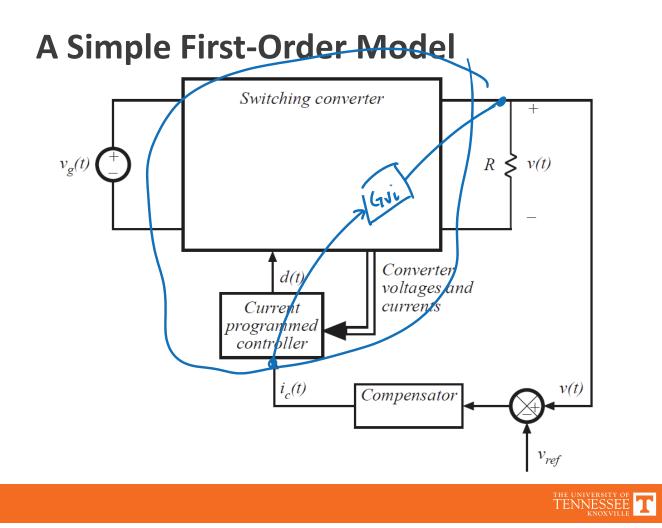


# **CPM Voltage Loop**



## **Current Programmed Control**

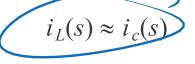
- Covered in Ch. 12 of *Fundamentals of Power Electronics*
- Advantages of current programmed control:
  - Simpler dynamics —inductor pole is moved to high frequency
  - Simple robust output voltage control, with large phase margin, can be obtained without use of compensator lead networks
  - Transistor failures due to excessive current can be prevented simply by limiting  $i_c(t)$
  - It is always necessary to sense the transistor current, to protect against overcurrent failures
  - Transformer saturation problems in bridge or push-pull converters can be mitigated
- A disadvantage: susceptibility to noise



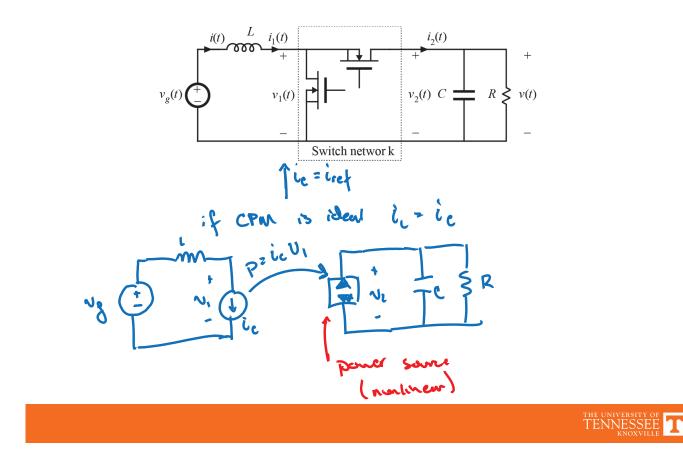
## **The First-Order Approximation**

$$\left\langle i_L(t) \right\rangle_{T_s} = i_c(t)$$

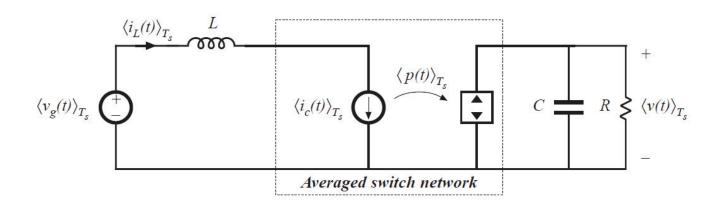
- Neglects switching ripple
- Yields physical insight and simple first-order model
- Accurate when converter operates well into CCM (so that switching ripple is small
- Accurate when artificial ramp (discussed later) is small
- Resulting small-signal relation:



# **Averaged Modeling**

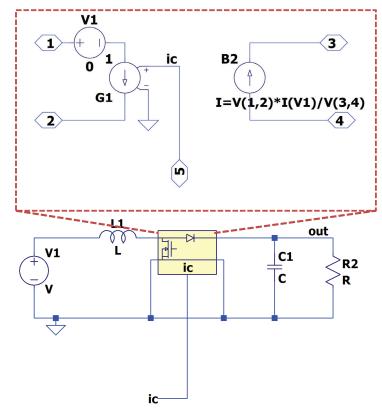


## **Large-Signal Nonlinear Model**

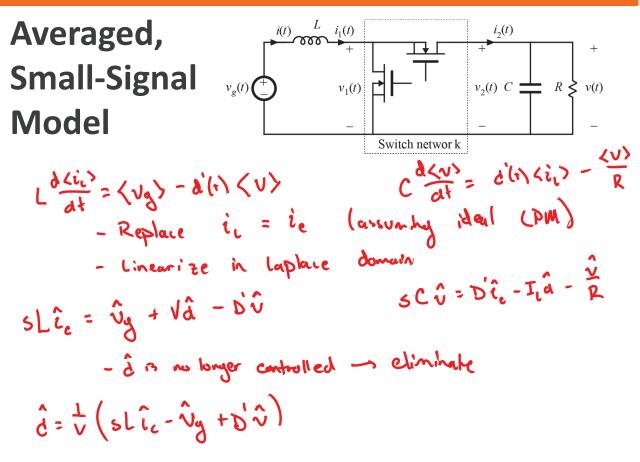


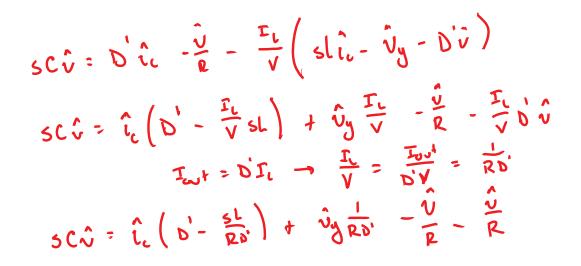


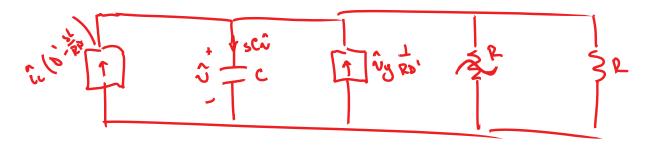
# **Implementation in LTSpice**



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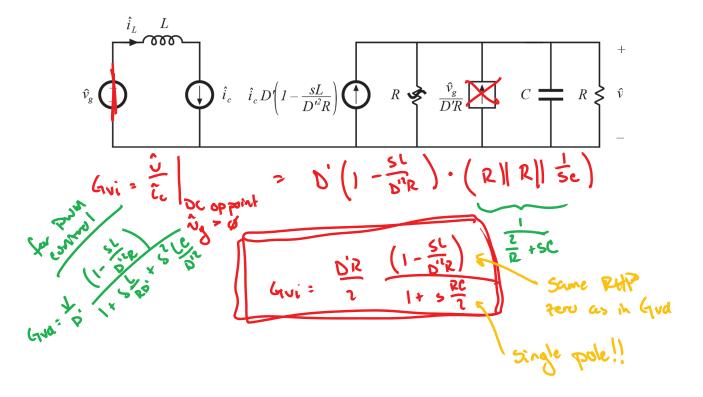




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#### **Boost CCM CPM Small-Signal Model**



## **CPM Transfer Functions**

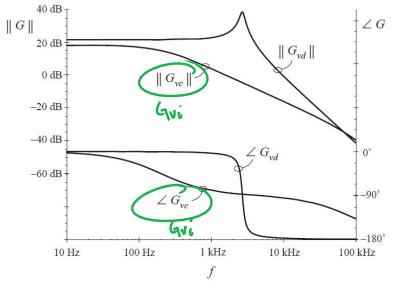
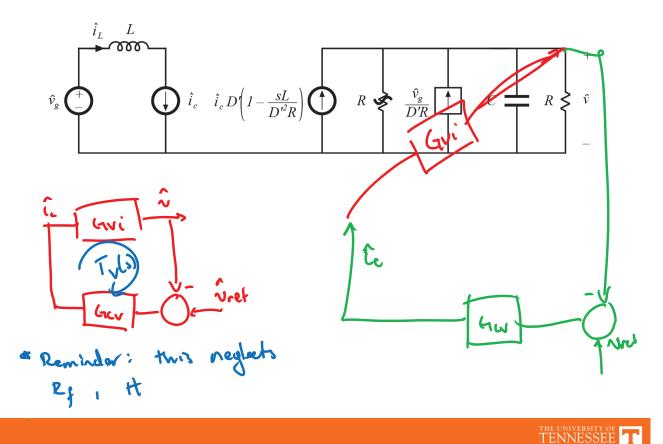


Fig. 12.28 Comparison of CPM control with duty-cycle control, for the control-to-output frequency response of the buck converter example.



#### **Voltage Control**

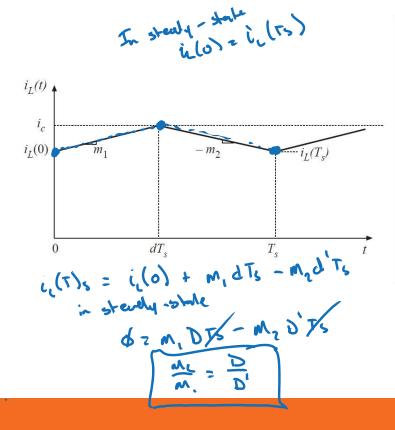


# **CPM Oscillations for D>0.5**

- The current programmed controller is inherently unstable for D > 0.5, regardless of the converter topology
- Controller can be stabilized by addition of an artificial ramp

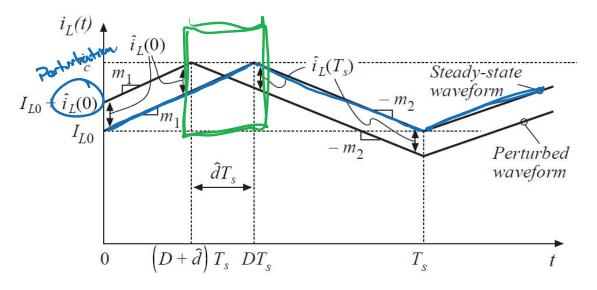


## **Inductor Current Waveform in CCM**



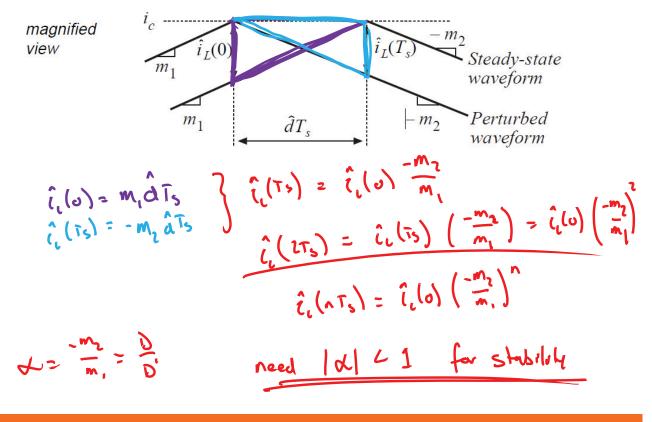
Inductor current slopes $m_1$ and $-m_2$					
buck converter					
$m_1 = \frac{v_g - v}{L}$	$-m_2 = -\frac{v}{L}$				
boost converter					
$m_1 = \frac{v_g}{L}$	$-m_2 = \frac{v_g - v}{L}$				
buck–boost converter					
$m_1 = \frac{v_g}{L}$	$-m_2 = \frac{v}{L}$				

### **Introducing a Perturbation**

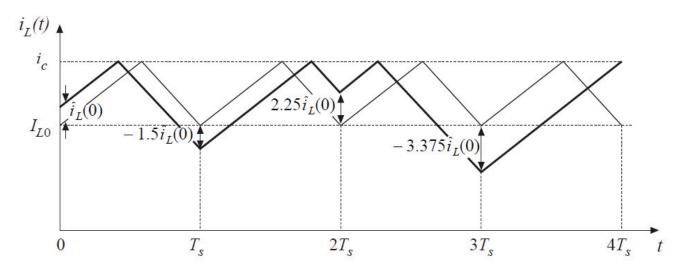


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#### Change in Inductor Current Over $T_s$

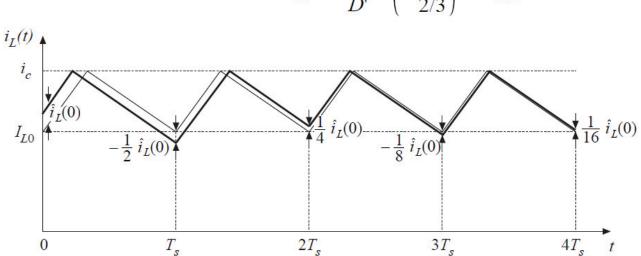






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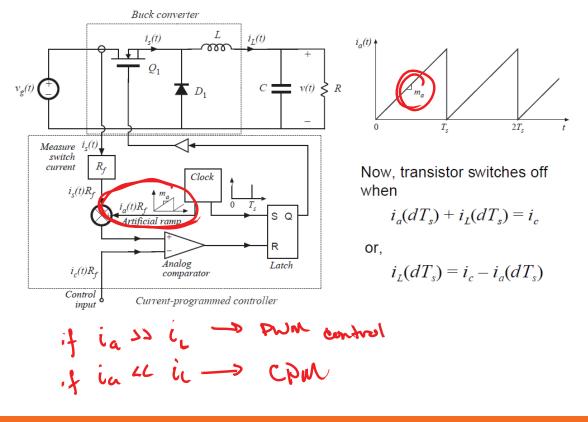
Example: Stable operation for *D*=1/3



 $\alpha = -\frac{D}{D'} = \left(-\frac{1/3}{2/3}\right) = -0.5$ 

$$\alpha = -\frac{D}{D'} = \left(-\frac{0.6}{0.4}\right) = -1.5$$

# **Stabilization Through Artificial Ramp**



## **Final Value of Inductor Current**

First subinterval:

 $\hat{i}_L(0) = -\hat{d}T_s \left( m_1 + m_a \right)$ 

Second subinterval:

$$\hat{i}_L(T_s) = -\hat{d}T_s \left(m_g - m_2\right)$$

Net change over one switching period:

$$\hat{i}_{L}(T_{s}) = \hat{i}_{L}(0) \left(-\frac{m_{2}-m_{a}}{m_{1}+m_{a}}\right)$$

After *n* switching periods:



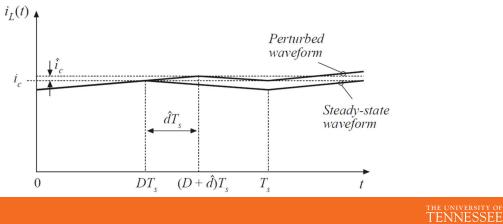
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# **Artificial Ramp: Additional Notes**

- For stability, require  $|\alpha| < 1$
- Common choices:

$$\alpha = -\frac{1 - \frac{m_a}{m_2}}{\frac{D'}{D} + \frac{m_a}{m_2}}$$

- $-m_a = 0.5 m_2$  (stable for all duty cycles)
- $-m_a = m_2$  (deadbeat)
- Artificial ramp decreases sensitivity to noise



# **More Accurate Models**

- The simple models of the previous section yield insight into the low- frequency behavior of CPM converters
- Unfortunately, they do not always predict everything that we need to know:
  - Line-to-output transfer function of the buck converter
  - Dynamics at frequencies approaching  $f_s$
- More accurate model accounts for nonideal operation of current mode controller built-in feedback loop
- Converter duty-cycle-controlled model, plus block diagram that accurately models equations of current mode controller
- See Section 12.3 for additional info

## More Accurate Model

- Simple model assumes  $i_L = i_c$  always
- Accounting for ripple, and artificial ramp weakens this approximation it my bandwidte of voltage loop is well below tsh then it ≈ ic apples
- Using sampled data modeling

$$\frac{\hat{i}_L}{\hat{i}_C} = \frac{1}{1 + \frac{1}{Q_s} \left(\frac{s}{2\pi f_s/2}\right) + \left(\frac{s}{2\pi f_s/2}\right)^2}$$

Where

$$Q_s = \frac{2}{\pi \left(\frac{2}{1-\alpha} - 1\right)}$$

F. Dong Tan and R. D. Middlebrook, "A Unified Model for Current Programmed Converters," IEEE Transactions on Power Electronics, vol. 10, no. 4, July 1995.

## **Note: Comparison to Datasheet**

o can be calcu  $\frac{dI_1}{dI_0} = 1 - \frac{1}{K}$ 

dlo

Application Information (continued)

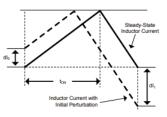
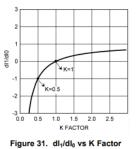


Figure 30. Effect of Initial Perturbation when dl<sub>1</sub>/dl<sub>0</sub> < -1



een dl<sub>1</sub>/dl<sub>0</sub> and K factor is illustrated in the graphic below.



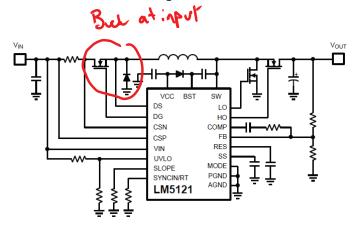
The absolute minimum value of K is 0.5. When K<0.5, the amplitude of dl<sub>1</sub> is greater than the amplitude of dl<sub>0</sub> and any initial perturbation results in sub-harmonic oscillation. If K=1, any initial perturbation will be removed in one switching cycle. This is known as one-cycle damping. When -1<dl<sub>1</sub>/dl<sub>0</sub><0, any initial perturbation will be under-damped. Any perturbation will be over-damped when 0<dl<sub>1</sub>/dl<sub>0</sub><1.



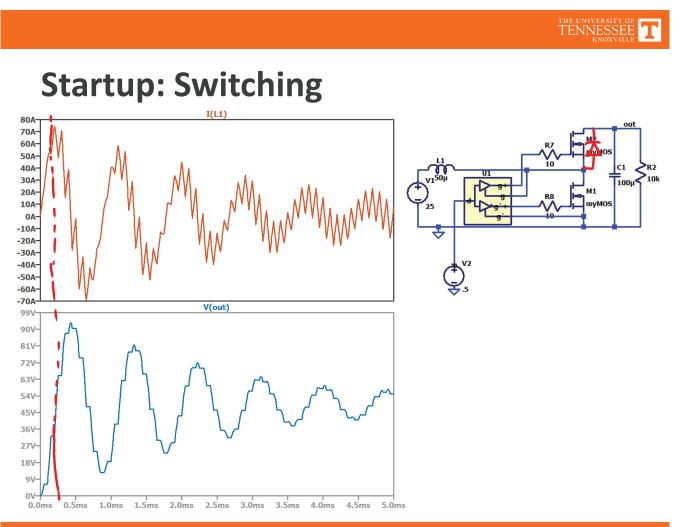
(19)

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## **Application to Experiment 4**

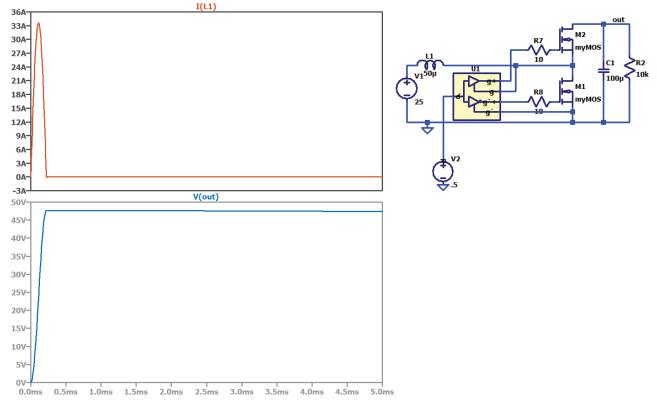


- Complex switching controller
- Read the datasheet first



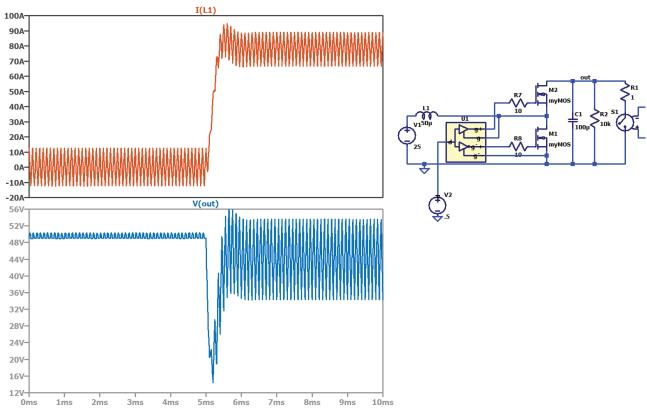


## **Startup: No Switching**



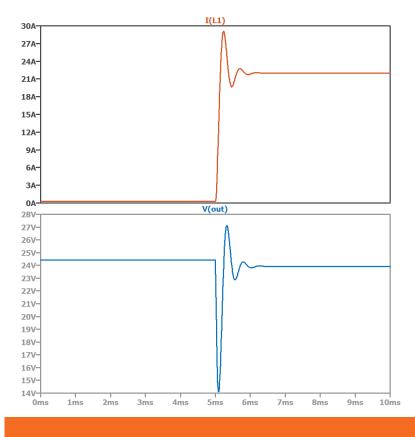


# **Short-Circuit: Switching**



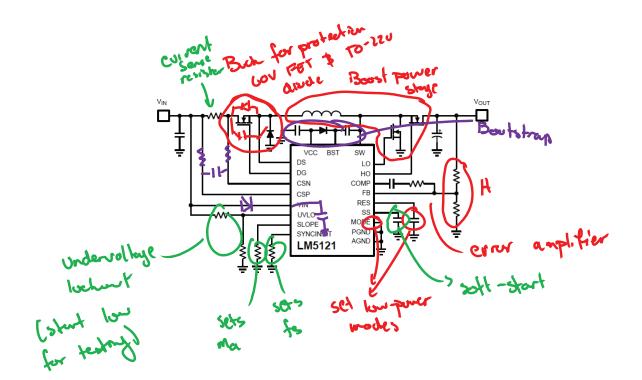


# **Short-Circuit: No Switching**

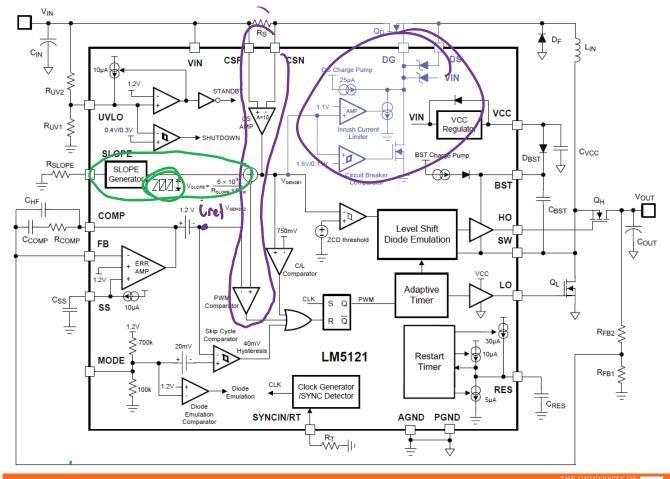




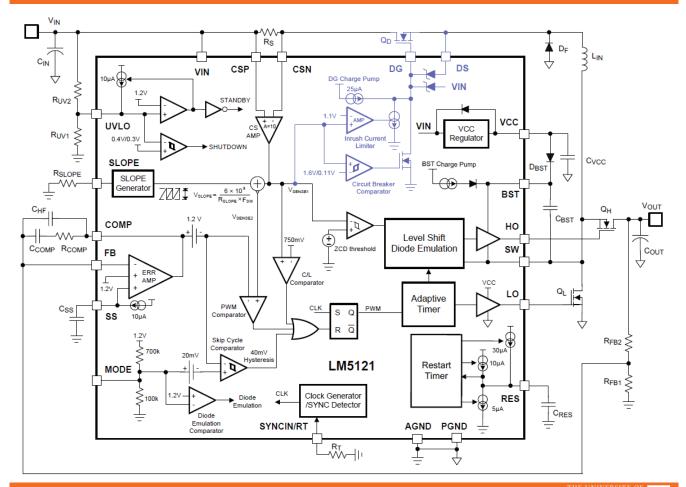
## LM5121: Functionality



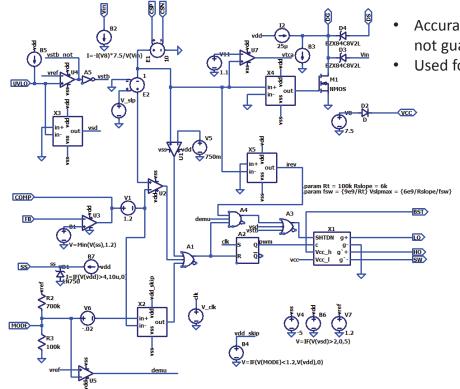




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# **Internal Functional Model in LTSpice**



 Accuracy/functionality not guaranteed

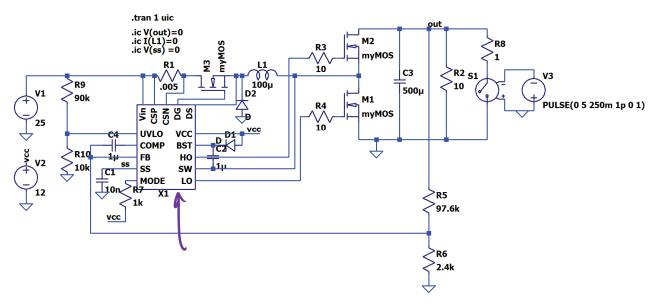
Used for insight only

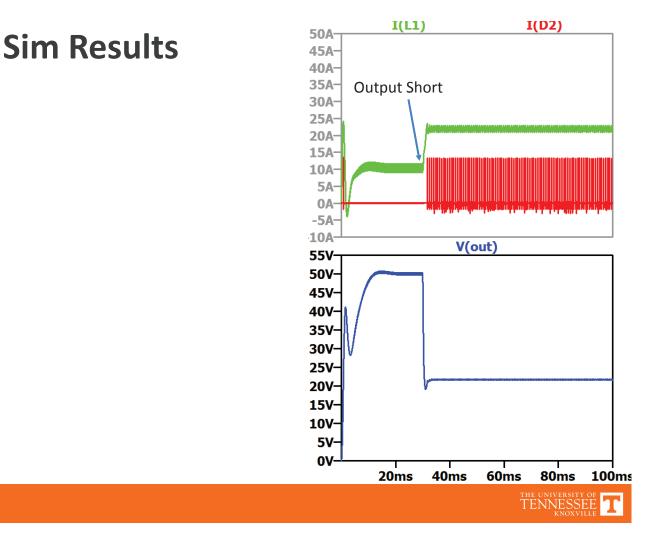


## **In-Circuit Simulation**

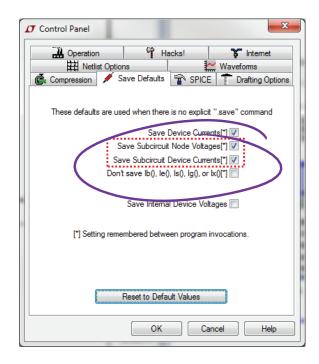
.model mysw sw(Von=3 Voff=2 Ron=.1 Roff = 1Meg)

.model myMOS VDMOS(Rg=1 Vto=4.5 Rd=14m Rs=10m Rb=17m Kp=30 Cgdmax=.5p Cgdmin=.05n Cgs=.2n Cjo=.03p Is=88p)



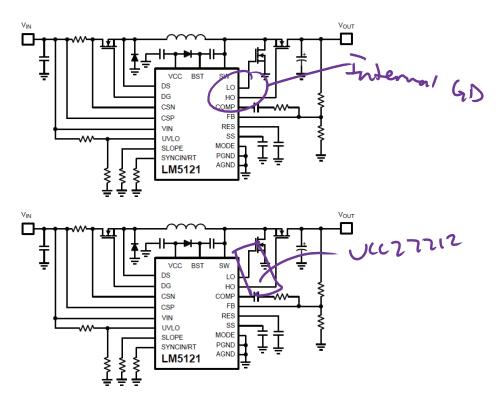


#### **A Tip: Debug Internal of Subcircuit**





# **Experiment 4: Gate Driver Selection**

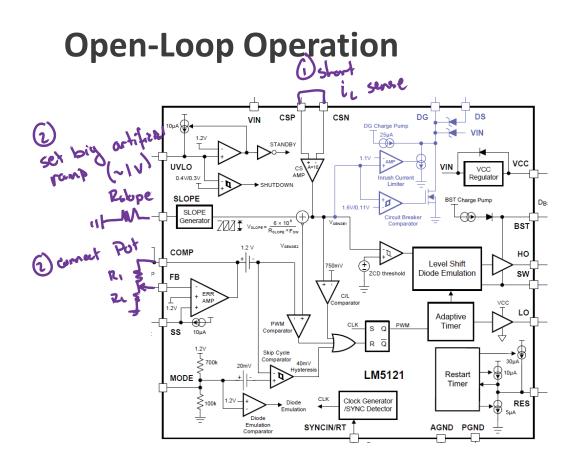


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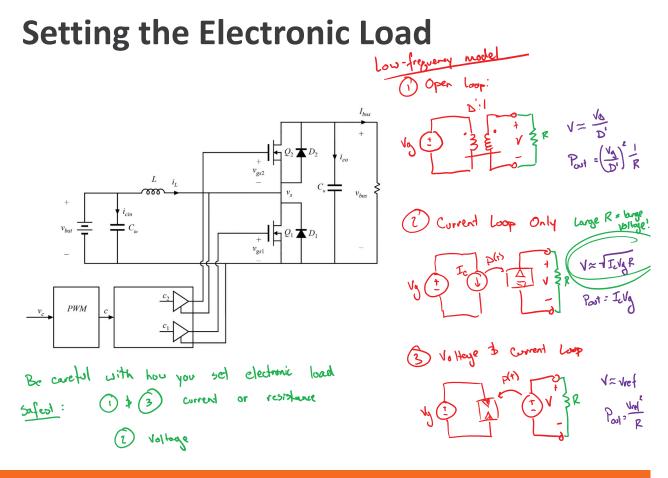
## **Experiment 4: Closing the Loop**

- Closed-loop operation in steps
  - 1. Open-loop operation with LM5121 modulator
    - Requires "tricking" LM5121
  - 2. Closed-loop current regulation
    - 3. Closed-loop voltage and current regulation









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